

## S6D06065F

### 6A 650V SIC POWER SCHOTTKY RECTIFIERS



ITO-220AC(TO-220MF-2L)

#### Description

This 650V 6A diode is a high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S6D06065F is ideal for energy sensitive, high frequency applications in challenging environments.

#### Circuit Diagram



#### Features

- 175°C TJ operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- “-A” is an AEC-Q101 qualified device
- Pb - Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

#### Applications

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

## Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage	$V_{RRM}$	-	650	V
Working Peak Reverse Voltage	$V_{RVM}$			
DC Blocking Voltage	$V_{DC}$			
Average Rectified Forward Current	$I_{F(AV)1}$	$T_c=25^\circ C$	16	A
	$I_{F(AV)2}$	$T_c=115^\circ C$	8	A
	$I_{F(AV)3}$	$T_c=135^\circ C$	6	A
Repetitive Peak Forward Surge Current	$I_{FRM1}$	10ms, Half Sine pulse, $T_c=25^\circ C$	31	A
	$I_{FRM2}$	10ms, Half Sine pulse, $T_c=110^\circ C$	19	A
Peak One Cycle Non-Repetitive Surge Current	$I_{FSM1}$	10ms, Half Sine pulse, $T_c=25^\circ C$	52	A
	$I_{FSM2}$	10ms, Half Sine pulse, $T_c=110^\circ C$	32	A
Non-Repetitive Peak Forward Surge Current	$I_{F,Max1}$	10μs. Pulse, $T_c=25^\circ C$	520	A
	$I_{F,Max2}$	10μs. Pulse, $T_c=110^\circ C$	470	A
Power Dissipation	$P_{tot1}$	$T_c=25^\circ C$	41	W
	$P_{tot2}$	$T_c=110^\circ C$	17	W
Mounting Torque		M3 Screw	1	Nm
		6-32 Screw	8.8	bf-in

## Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@ 6A, Pulse, $T_j = 25^\circ C$	1.27	1.5	V
	$V_{F2}$	@ 6A, Pulse, $T_j = 175^\circ C$	1.4	1.6	V
Reverse Current*	$I_{R1}$	$\@V_R = \text{rated } V_R$ $T_j = 25^\circ C$	0.3	3	uA
	$I_{R2}$	$\@V_R = \text{rated } V_R$ $T_j = 175^\circ C$	6	25	uA
Junction Capacitance	$C_T$	$V_R=0V, T_j=25^\circ C, f=1MHz$	559	-	pF
Reverse Recovery Charge	$Q_c$	$I_F = 6A, dI/dt = 200A/\mu s$ $VR = 400 V, T_j = 25^\circ C$	34.87	-	nC
Capacitance Stored Energy	EC	$VR = 400 V, T_j = 25^\circ C$	8.54	-	μJ

\* Pulse width < 300 μs, duty cycle < 2%

## Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	$T_j$	-	-55 to +175	°C
Storage Temperature	$T_{stg}$	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	3.6	°C/W

## Ratings and Characteristics Curves

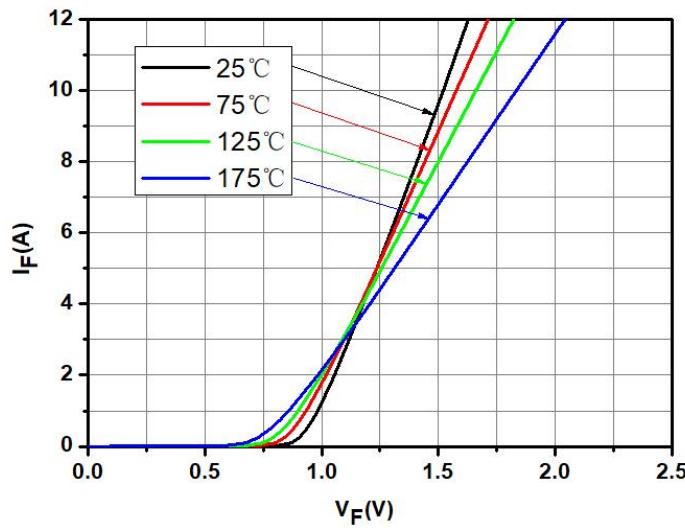


Fig.1-Typical Forward Voltage

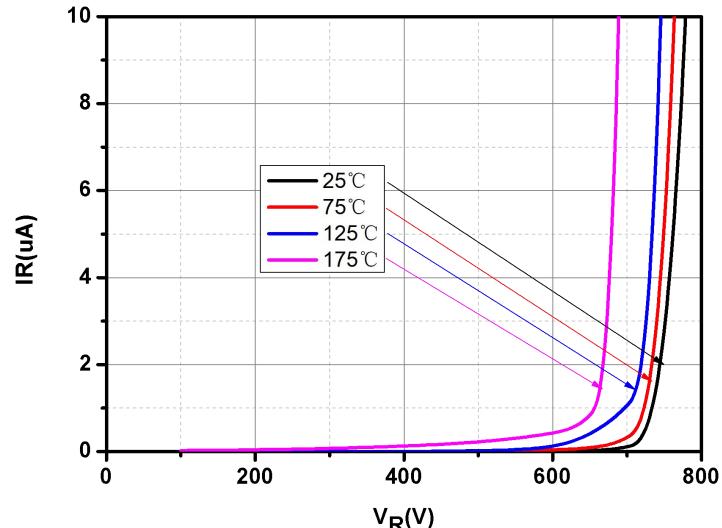


Fig.2-Typical Reverse Characteristics

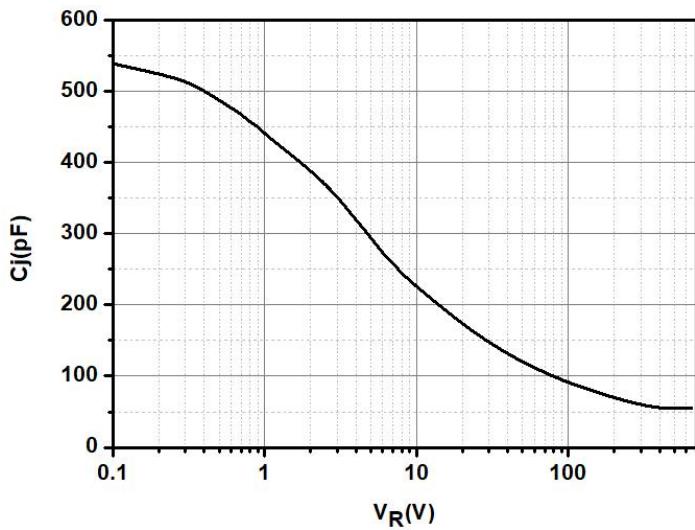


Fig.3-Capacitance vs. Reverse Voltage

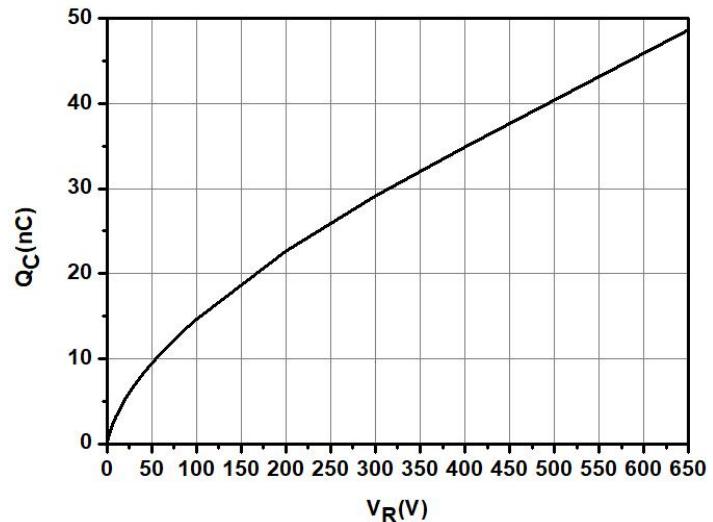


Fig.4-Total Capacitance Charge vs. Reverse Voltage

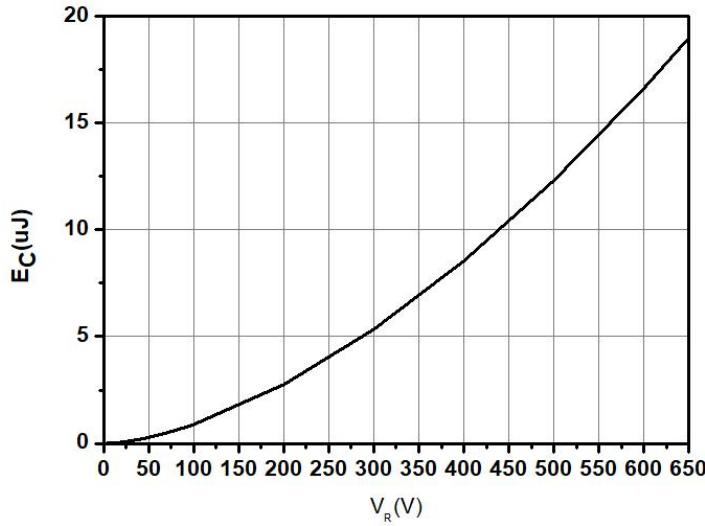


Fig.5-Capacitance Stored Energy

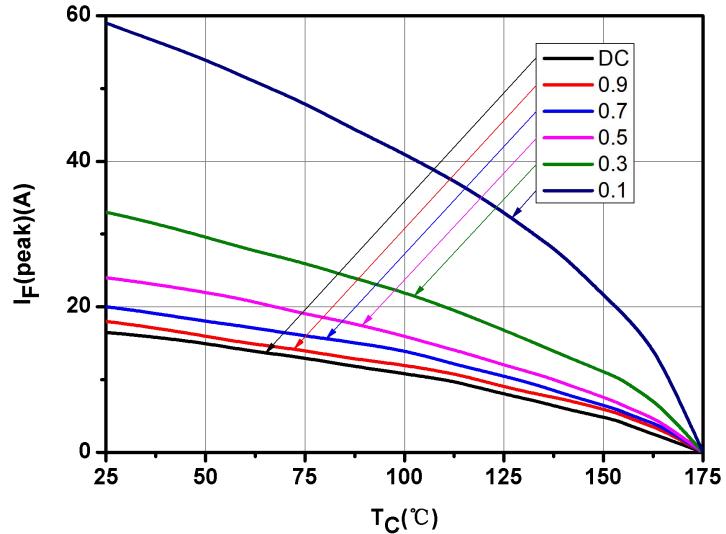


Fig.6-Current Derating

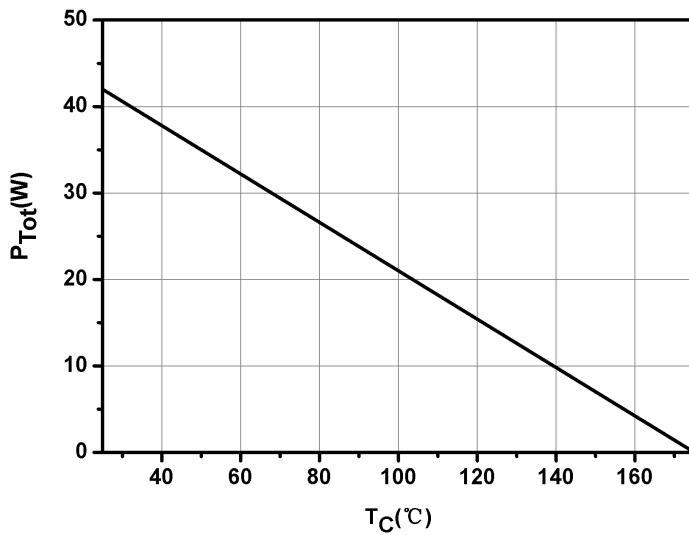
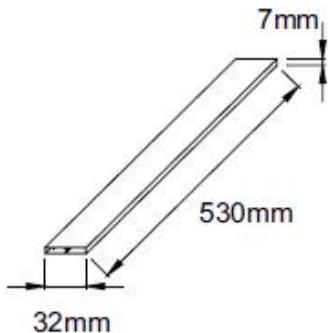


Fig.7-Power Derating

## Ordering Information

Device	Package	Shipping
S6D06065F	TO-220MF-2L(TO-220-F2)	50pcs / tube

## Tube Specification



## Marking Diagram

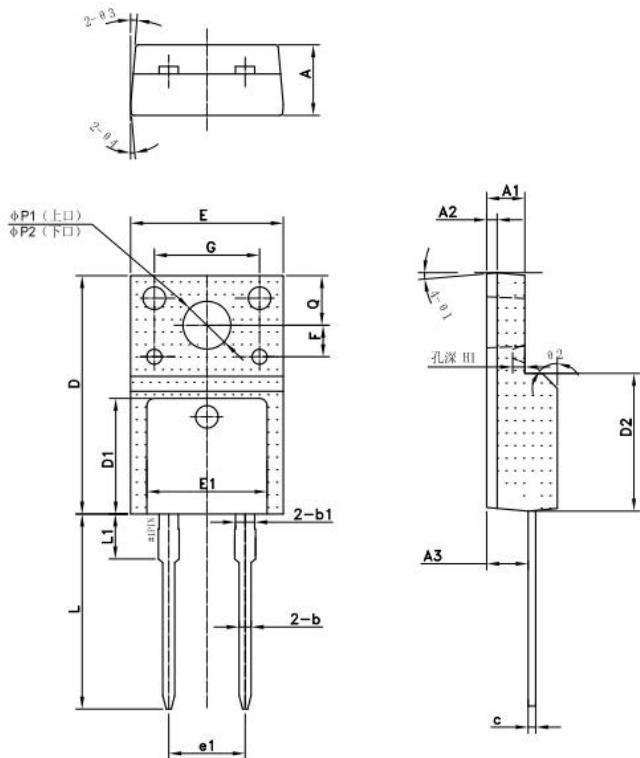


Where XXXXX is YYWWL

S6D	= Device Type
F	= Package type
06	= Forward Current (6A)
065	= Reverse Voltage (650V)
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

**Cautions:** Molding resin  
 Epoxy resin UL:94V-0

## Mechanical Dimensions



Symbol	Dimensions in millimeters		
	Min.	Typical	Max.
A	4.50	4.70	4.90
A1	2.34	2.54	2.74
A2		0.70	
A3	2.56	2.76	2.96
b	0.70	0.80	0.95
b1		1.28	
c	0.45	0.50	0.65
D	15.67	15.87	16.07
D1		7.70	
D2		9.12	
E	9.96	10.16	10.36
E1		8.00	
e1		5.08	
F		2.1	
G		7	
H1		0.81	
L	12.48	12.98	13.20
L1		2.93	
ΦP1 (上口)	2.98	3.18	3.38
ΦP2 (下口)	3.20	3.40	3.60
Q	3.10	3.30	3.50
θ1		5°	
θ2		45°	
θ3		5°	
θ4		5°	

**Technical Data**  
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